DATA SHEET

NEC

LASER DIODE

NX8300BE-CC,NX8300CE-CC

1 310 nm InGaAsP MQW-DFB LASER DIODE COAXIAL MODULE FOR 2.5 Gb/s

DESCRIPTION

The NX8300BE-CC and NX8300CE-CC are 1 310 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode coaxial modules with an internal optical isolator.

These modules are ideal as a light source for Synchronous Digital Hierarchy (SDH) system, STM-16, short-haul S-16.1 and long-haul L-16.1 ITU-T recommendations.

FEATURES

- Internal optical isolator
- High-speed response t_r = 40 ps, t_f = 100 ps
- Peak emission wavelength λ_p = 1 310 nm
- Optical output power P_f = 2.0 mW
- Wide operating temperature range T_C = 0 to +75°C
- InGaAs monitor PIN-PD
- With SC-UPC connector
- Based on Telcordia reliability

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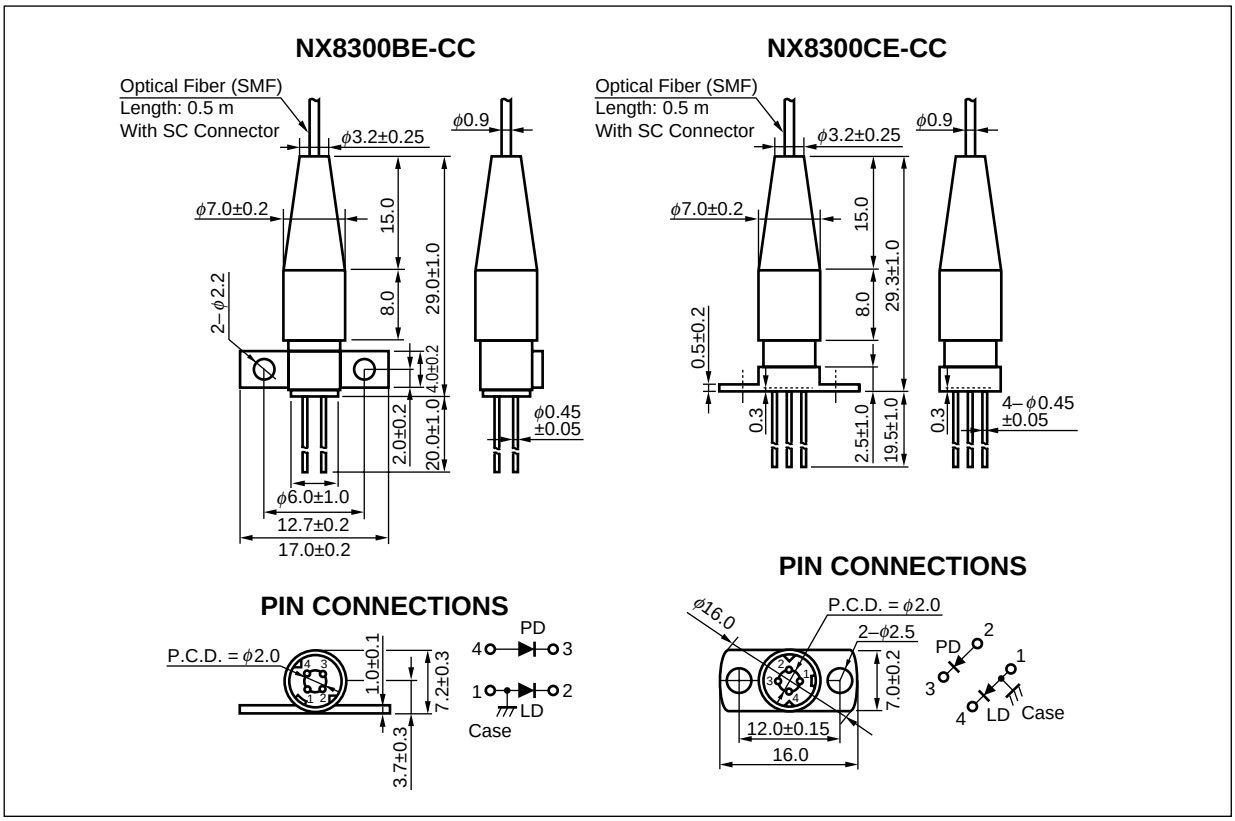
Printed in Japan

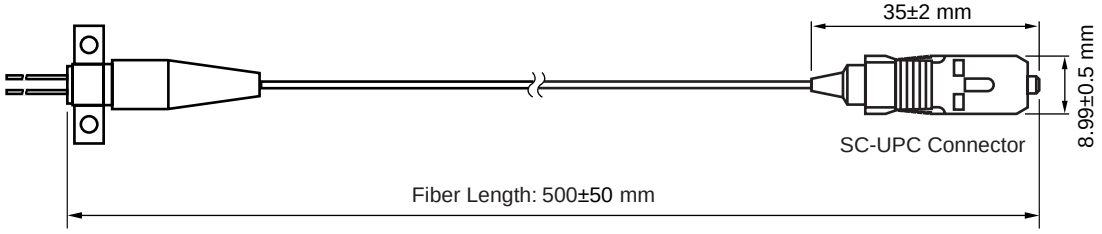
The mark ★ shows major revised points.

PACKAGE DIMENSIONS (UNIT : mm)



OPTICAL FIBER CHARACTERISTICS

Parameter	Specification	Unit
Mode Field Diameter	9.5±1	μm
Cladding Diameter	125±2	μm
Maximum Cladding Noncircularity	2	%
Maximum Core/Cladding Concentricity	1.6	%
Outer Diameter	0.9±0.1	mm
Cut-off Wavelength	1 100 to 1 270	nm
Minimum Fiber Bending Radius	30	mm
Fiber Length	500±50	mm
Flammability	UL1581 VW-1	



ORDERING INFORMATION

Part Number	Flange Type	Available Connector
NX8300BE-CC	Flat Mount Flange	With SC-UPC Connector
NX8300CE-CC	Vertical Mount Flange	

ABSOLUTE MAXIMUM RATINGS

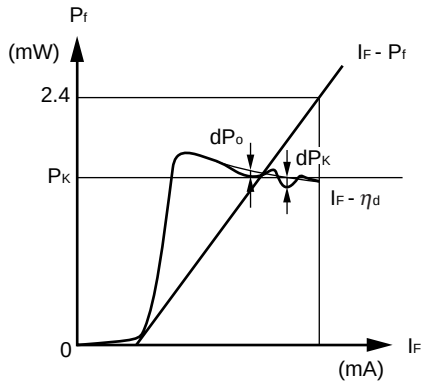
Parameter	Symbol	Ratings	Unit
Optical Output Power from Fiber	P_f	5	mW
Forward Current of LD	I_F	150	mA
Reverse Voltage of LD	V_R	2.0	V
Forward Current of PD	I_F	2.0	mA
Reverse Voltage of PD	V_R	15	V
Operating Case Temperature	T_C	0 to +75	°C
Storage Temperature	T_{stg}	−40 to +85	°C
Lead Soldering Temperature	T_{sld}	260 (10 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

ELECTRO-OPTICAL CHARACTERISTICS (T_C = 0 to +75°C, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Optical Output Power from Fiber	P_f	CW		2.0		mW
Operating Voltage	V_{op}	P_f = 2.0 mW		1.2	1.6	V
Threshold Current	I_{th}	T_C = 25°C		15	25	mA
					45	
Threshold Output Power	P_{th}	$I_F = I_{th}$			50	μW
Modulation Current	I_{mod}	P_f = 2.0 mW, T_C = 25°C	11	20	35	mA
		P_f = 2.0 mW	10		40	
Differential Efficiency	η_d	P_f = 2.0 mW, T_C = 25°C	0.060	0.100	0.150	W/A
		P_f = 2.0 mW	0.050		0.200	
Temperature Dependence of Differential Efficiency	$\Delta\eta_d$	$\Delta\eta_d = 10 \log \frac{\eta_d \text{ (@ } T_C \text{ °C)}}{\eta_d \text{ (@ 25°C)}}$	–3	–1.6		dB
Kink (Refer to **DEFINITIONS**)	kink	P_f = Up to 2.4 mW			±20	%
Peak Emission Wavelength	λ_p	P_f = 2.0 mW	1 285	1 310	1 330	nm
Temperature Dependence of Peak Emission Wavelength	$\Delta\lambda/\Delta T$			0.09	0.1	nm/°C
Spectral Width	$\Delta\lambda$	P_f = 2.0 mW, –20 dB down width		0.1	1.0	nm
Side Mode Suppression Ratio	SMSR	P_f = 2.0 mW	30	40		dB
Relaxation Oscillation Frequency	f_r	P_f = 2.0 mW		8.0		GHz
Rise Time	t_r	10-90%, P_{pk} = 2.0 mW, $I_F = I_{th}$		40	125	ps
Fall Time	t_f	90-10%, P_{pk} = 2.0 mW, $I_F = I_{th}$		100	200	ps
Monitor Current	I_m	V_R = 5 V, P_f = 2.0 mW	100	500	1 000	μA
Monitor Dark Current	I_D	V_R = 5 V, T_C = 25°C		0.1	50	nA
		V_R = 5 V		10	500	
Monitor PD Terminal Capacitance	C_t	V_R = 5 V, f = 1 MHz		1.0	20	pF
Linearity (Refer to **DEFINITIONS**)	LIN_m	V_R = 5 V, P_f = 0.2 to 2.0 mW			10	%
Tracking Error (Refer to **DEFINITIONS**)	γ	I_m = const.		0.5	1.0	dB

★ PARAMETER DEFINITIONS

Kink : kink

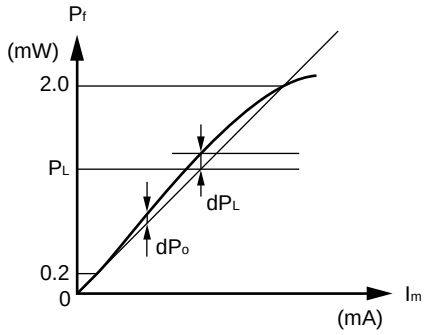


$$kink = \frac{|dP_K|}{P_K} \times 100\ [\%]$$

$dP_K = dP_o$ MAX.

$P_K \leq 2.4$ (mW)

Linearity : LIN_m

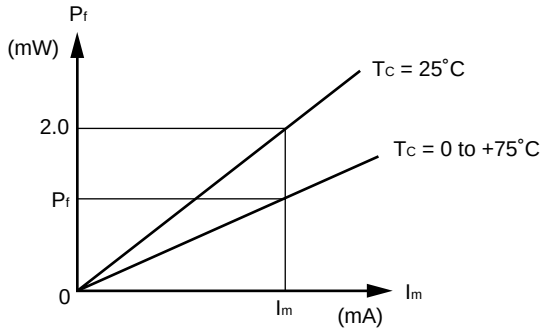


$$LIN_m = \frac{|dP_L|}{P_L} \times 100\ [\%]$$

$dP_L = dP_o$ MAX.

$0.2 < P_L < 2.0$ (mW)

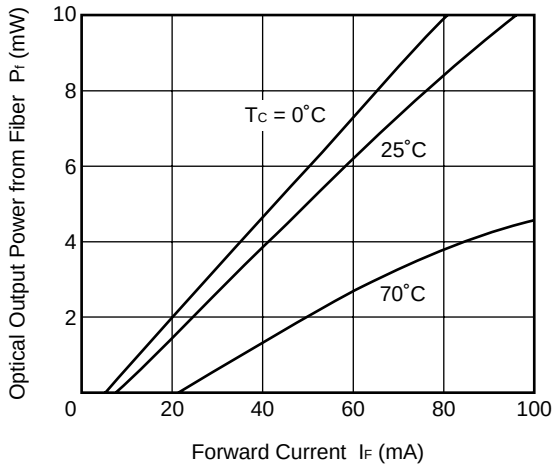
Tracking Error : γ



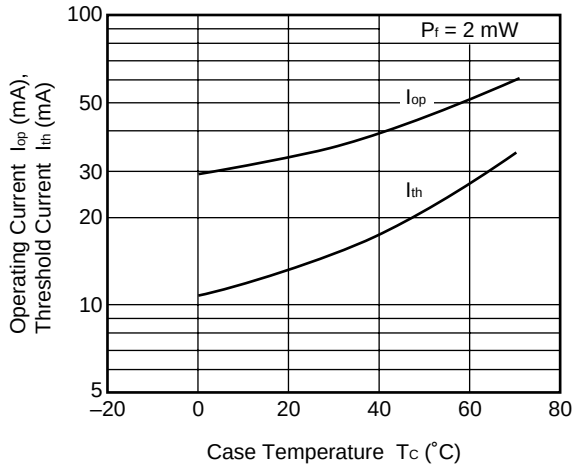
$$\gamma = \left| 10 \log \frac{P_f}{2.0} \right| [dB]$$

TYPICAL CHARACTERISTICS (T_C = 25°C, unless otherwise specified)

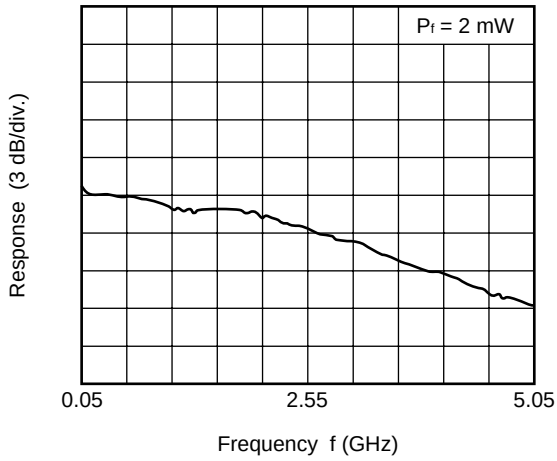
OPTICAL OUTPUT POWER FROM FIBER vs. FORWARD CURRENT



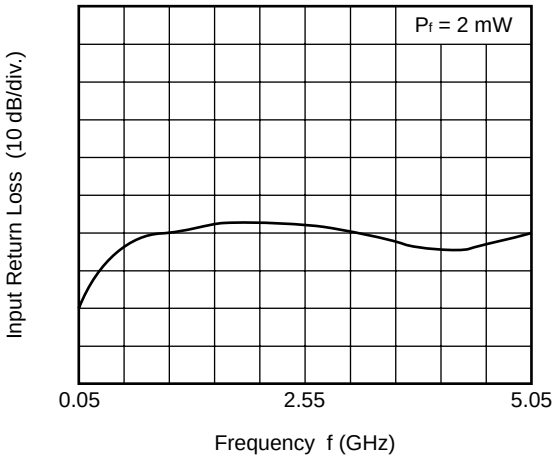
OPERATING CURRENT AND THRESHOLD CURRENT vs. CASE TEMPERATURE



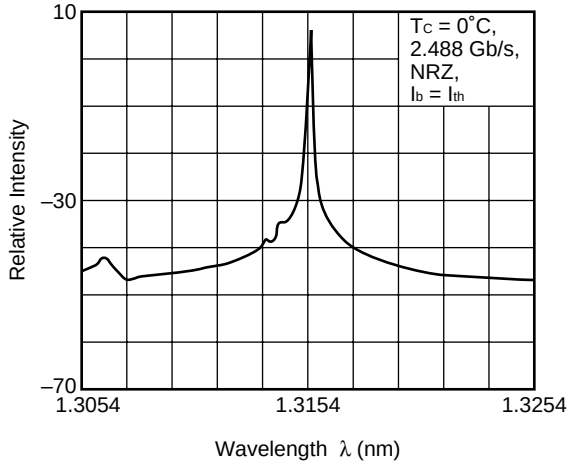
FREQUENCY RESPONSE (S_{21})



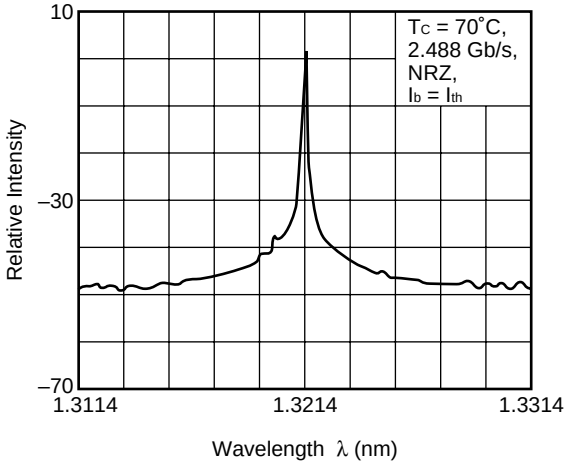
INPUT RETURN LOSS CHARACTERISTICS (S_{11})



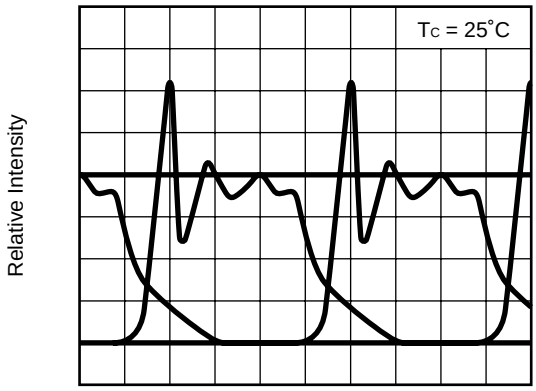
SPECTRUM



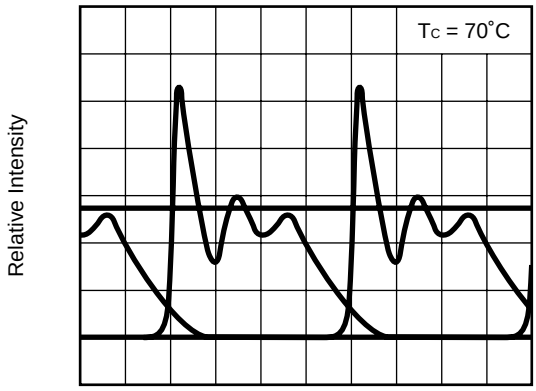
SPECTRUM



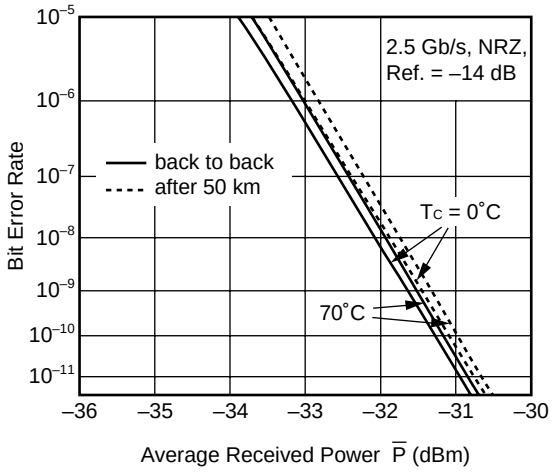
EYE DIAGRAM



EYE DIAGRAM



ERROR RATE CHARACTERISTICS



Remark The graphs indicate nominal characteristics.

DFB-LD FAMILY

	Part Number	Absolute Maximum Ratings		Electro-Optical Characteristics (T_C = 25°C)			Application	Package
		T_C (°C)	T_{stg} (°C)	I_{th} (mA)	P_f (mW)	λ_p (nm)		
				TYP.	MIN.	TYP.		
	NX8300BE-CC NX8300CE-CC	0 to +75	–40 to +85	15	2 *1	1 310	2.5 Gb/s: STM-16 (S-16.1, L-16.1)	Coaxial
	NX8303BG-CC NX8303CG-CC	–10 to +85	–40 to +85	15	2 *1	1 310	622 Mb/s: STM-4 (L-4.1)	Coaxial
★	NX8304BE-CC NX8304CE-CC	–40 to +85	–40 to +85	15	2 *1	1 310	For fiberoptic communications	Coaxial
	NX8503BG-CC NX8503CG-CC	–10 to +85	–40 to +85	15	2 *1	1 550	156 Mb/s: STM-1 (L-1.2, L-1.3) 622 Mb/s: STM-4 (L-4.2, L-4.3)	Coaxial
	NX8504BE-CC NX8504CE-CC	–10 to +85	–40 to +85	15	2 *1	1 550	622 Mb/s: STM-4 (L-4.2, L-4.3)	Coaxial
★	NX8560LJ-CC	–20 to +70	–40 to +85	6	–1 dBm	1 550 *2	≤ 10 Gb/s: STM-64	BFY with GPO™
	NX8562LB	–20 to +65	–40 to +85	20	20	1 550 *2	CW Light Source for external modulator	BFY
	NX8563LB	–20 to +65	–40 to +85	20	10	1 550 *2	CW Light Source for external modulator	BFY
★	NX8564LE-CC	–20 to +70	–40 to +85	7	–2 dBm *1	1 550 *2	2.5 Gb/s: STM-16, 360 km EA modulator integrated	BFY
★	NX8565LE-CC	–20 to +70	–40 to +85	7	–2 dBm *1	1 550 *2	2.5 Gb/s: STM-16, 600 km EA modulator integrated	BFY
★	NX8566LE-CC	–20 to +70	–40 to +85	7	0 dBm	1 550 *2	2.5 Gb/s: STM-16, 240 km EA modulator integrated	BFY
	NX8570 Series	–20 to +70	–40 to +85	20	20	1 550 *2	CW Light Source with λ monitoring PD	BFY
	NX8571 Series	–20 to +70	–40 to +85	20	10	1 550 *2	CW Light Source with λ monitoring PD	BFY

***1** TYP.

***2** Available for DWDM Wavelengths based on ITU-T recommendations

REFERENCE

Document Name	Document No.
Optical semiconducrtor devices for fiberoptic communications Selection Guide	P12480E
Opto-Electronics Devices Pamphlet	P13623E
Opto-Electronics Devices (CD-ROM)	P12944X
NEC semiconductor device reliability/quality control system [*1]	C11159E
Quality grades on NEC semiconductor devices [*1]	C11531E
SEMICONDUCTOR SELECTION GUIDE –Products and Packages– [*1]	X13769E

***1** Published by NEC Corporation

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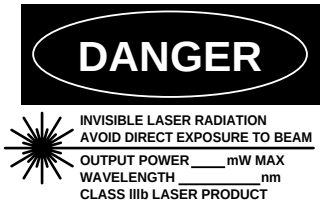
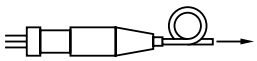
M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight. • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested. • Do not destroy or burn the product. • Do not cut or cleave off any part of the product. • Do not crush or chemically dissolve the product. • Do not put the product in the mouth. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.
Caution Optical Fiber	A glass-fiber is attached on the product. Handle with care. • When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.

▶Business issue

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▶Technical issue

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